

1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a CFP15 (SOT1289) power and flat lead Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

•

- Average forward current: $I_{F(AV)} \le 15 A$
- Reverse voltage: V_R ≤ 45 V
- Extremely low forward voltage
- · High power capability due to clip-bonding technology and heat sink
- Small and thin SMD power plastic package, typical height 0.78 mm
- AEC-Q101 qualified

3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Freewheeling application
- Reverse polarity protection
- Low power consumption application

4. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|-------------------------|---|-----|-----|-----|------|
| I _{F(AV)} | average forward current | δ = 0.5; f = 20 kHz; T _{sp} ≤ 160 °C; square wave | - | - | 15 | A |
| V _R | reverse voltage | T _j = 25 °C | - | - | 45 | V |
| V _F | forward voltage | $\label{eq:IF} \begin{array}{l} I_F = 15 \; A; t_p \leq 300 \; \mu s; \overline{o} \leq 0.02; \\ T_j = 25 \; ^\circ C; pulsed \end{array}$ | - | 430 | 490 | mV |
| I _R | reverse current | V_R = 10 V; $t_p \le 3$ ms; $\delta \le 0.3$; T _j = 25 °C; pulsed | - | 30 | 70 | μA |
| | | V_R = 45 V; $t_p \le 3$ ms; $\delta \le 0.3$; T_j = 25 °C; pulsed | - | 420 | 900 | μA |





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5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | А | anode | | |
| 2 | А | anode | | |
| 3 | к | cathode | | |
| | | | CFP15 (SOT1289) | |

6. Ordering information

| Table 3. Ordering in | formation | | |
|----------------------|-----------|---|---------|
| Type number | Package | | |
| | Name | Description | Version |
| PMEG045V150EPD | CFP15 | plastic, thermal enhanced ultra thin SMD package; 3 leads; body: 5.8 x 4.3 x 0.78 mm | SOT1289 |

7. Marking

| Table 4. Marking codes | |
|------------------------|--------------|
| Type number | Marking code |
| PMEG045V150EPD | 045V 150E |

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|--------------------|-------------------------------------|--|-----|-----|------|------|
| V _R | reverse voltage | T _j = 25 °C | | - | 45 | V |
| I _F | forward current | T _{sp} = 155 °C; δ = 1 | | - | 21 | А |
| I _{F(AV)} | average forward current | δ = 0.5; f = 20 kHz; T _{sp} ≤ 160 °C; square wave | | - | 15 | A |
| I _{FSM} | non-repetitive peak forward current | t_p = 8 ms; $T_{j(init)}$ = 25 °C; square wave | | - | 270 | A |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 1.66 | W |
| | | | [2] | - | 2.15 | W |
| | | | [3] | - | 3.75 | W |
| Tj | junction temperature | | | - | 175 | °C |
| T _{amb} | ambient temperature | | | -55 | 175 | °C |
| T _{stg} | storage temperature | | | -65 | 175 | °C |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

[3] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.

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9. Thermal characteristics

| Table 6. 1 | Thermal characteristics | | | | | | |
|-----------------------|--|-------------|--------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Тур | Мах | Unit |
| R _{th(j-a)} | thermal resistance | in free air | [1][2] | - | - | 90 | K/W |
| | from junction to ambient | | [1][3] | - | - | 70 | K/W |
| | ampient | | [1][4] | - | - | 40 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | [5] | - | - | 3 | K/W |

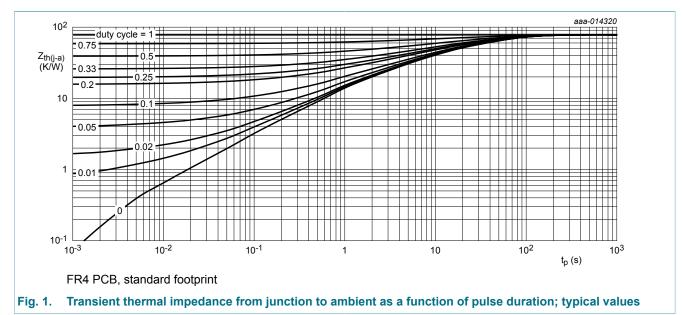
[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

[4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

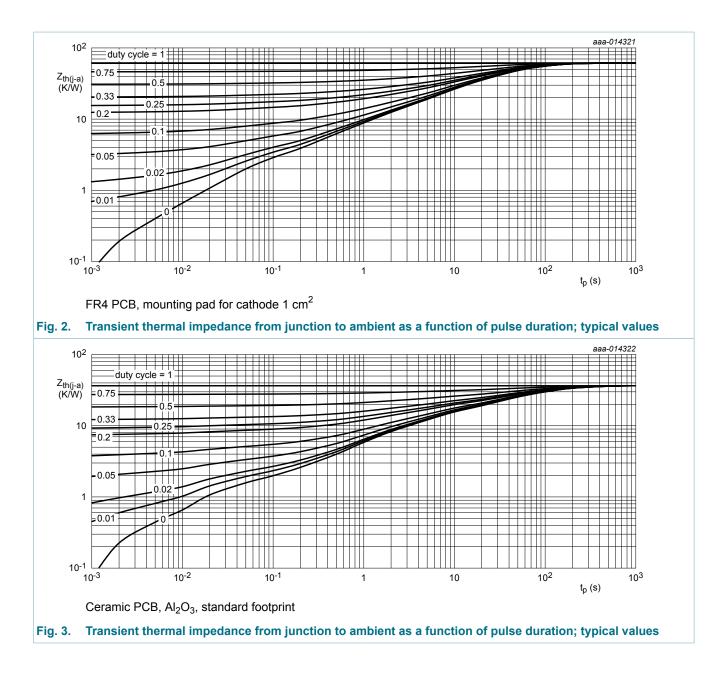
[5] Soldering point of cathode tab.



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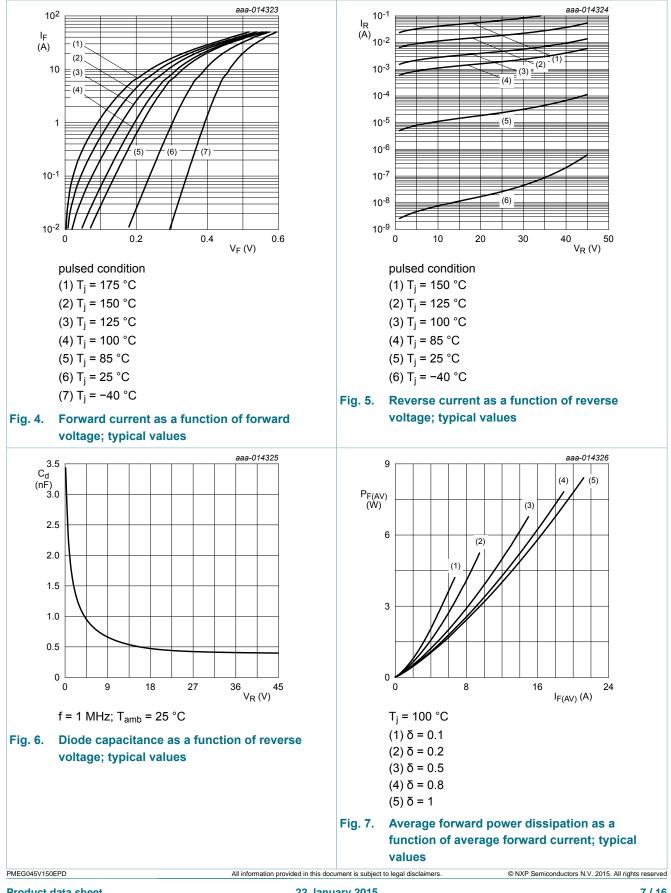


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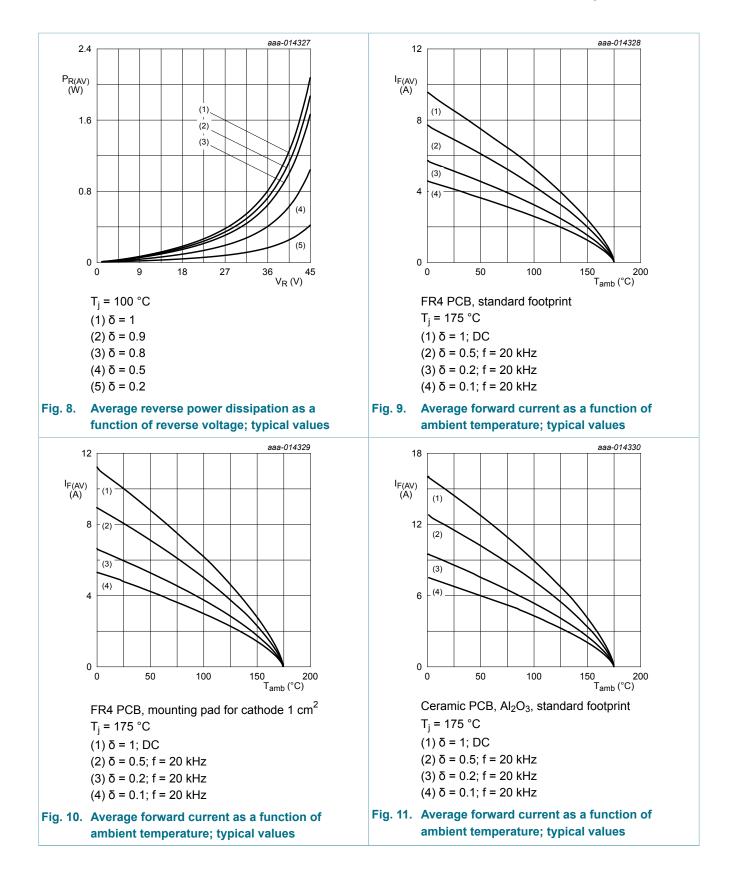
10. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|-------------------------------------|--|-----|------|-----|------|
| V _{(BR)R} | reverse breakdown voltage | $I_R = 5 \text{ mA}; T_j = 25 \text{ °C}; t_p \le 1.2 \text{ ms}; \delta \le 0.12; \text{ pulsed}$ | 45 | - | - | V |
| V _F | forward voltage | $\begin{split} I_F &= 1 \text{ A}; \ t_p \leq 300 \ \mu\text{s}; \ \delta \leq 0.02; \\ T_j &= 25 \ ^\circ\text{C}; \ \text{pulsed} \end{split}$ | - | 305 | 350 | mV |
| | | I_F = 5 A; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C; pulsed | - | 360 | 410 | mV |
| | | I_F = 10 A; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C; pulsed | - | 400 | - | mV |
| | | I_F = 15 A; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C; pulsed | - | 430 | 490 | mV |
| | | I_F = 15 A; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 125 °C; pulsed | - | 335 | - | mV |
| I _R | reverse current | V_R = 5 V; $t_p \le 3$ ms; $\delta \le 0.3$; T_j = 25 °C; pulsed | - | 20 | - | μA |
| | | $V_{R} = 10 \text{ V}; t_{p} \le 3 \text{ ms}; \delta \le 0.3;$ T _j = 25 °C; pulsed | - | 30 | 70 | μA |
| | | V_R = 30 V; $t_p \le 3$ ms; $\delta \le 0.3$; T _j = 25 °C; pulsed | - | 90 | - | μA |
| | | V_R = 45 V; $t_p \le 3$ ms; $\delta \le 0.3$; T _j = 25 °C; pulsed | - | 420 | 900 | μA |
| C _d | diode capacitance | V _R = 1 V; f = 1 MHz; T _j = 25 °C | - | 1870 | - | pF |
| | | V _R = 10 V; f = 1 MHz; T _j = 25 °C | - | 610 | - | pF |
| t _{rr} | reverse recovery time step recovery | I _F = 0.5 A; I _R = 0.5 A; I _{R(meas)} = 0.1 A; T _j = 25 °C | - | 54 | - | ns |
| t _{rr} | reverse recovery time ramp recovery | dI _F /dt = 200 A/µs; T _j = 25 °C; I _F = 6 A; V _R = 26 V | - | 19 | - | ns |
| V _{FRM} | peak forward recovery voltage | $I_F = 0.5 \text{ A}; \text{ d}I_F/\text{d}t = 20 \text{ A}/\mu\text{s}; T_j = 25 ^\circ\text{C}$ | - | 294 | - | mV |

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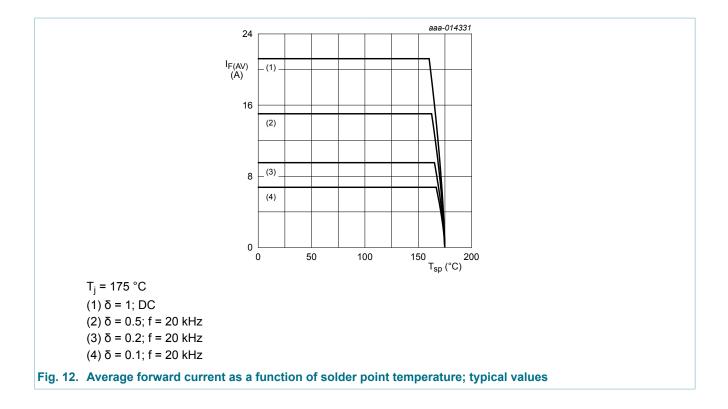
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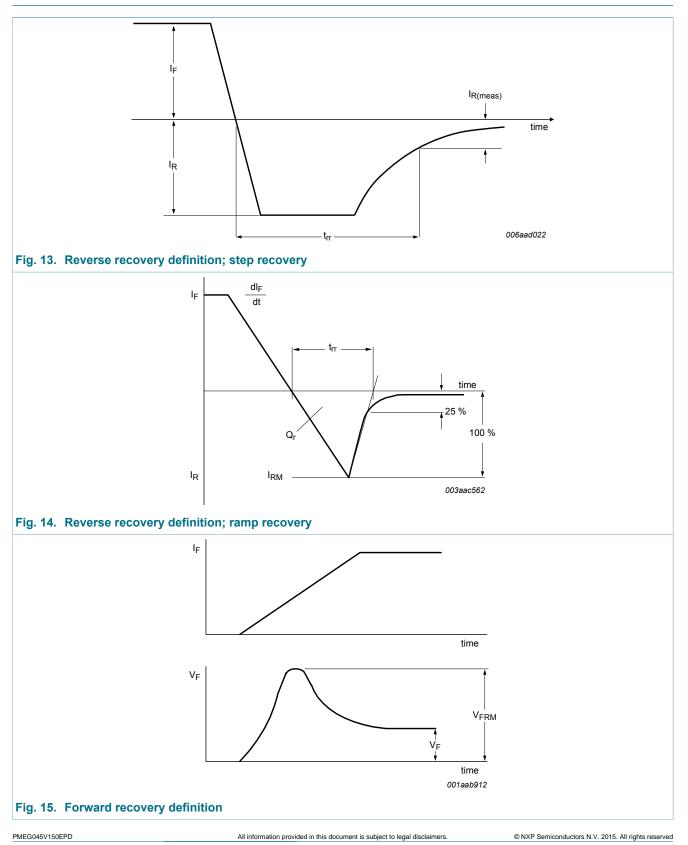
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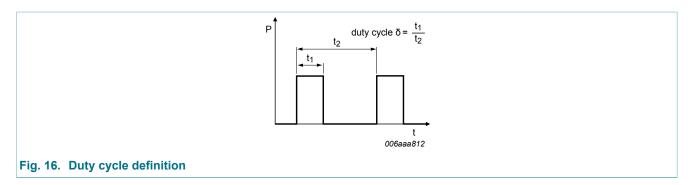


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11. Test information



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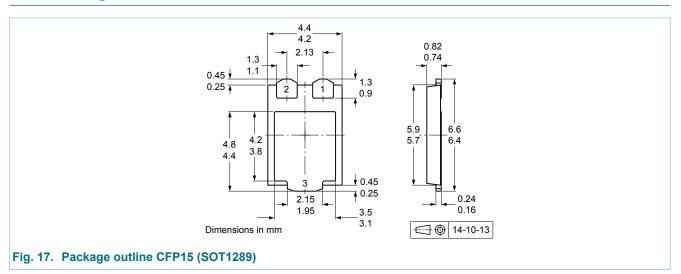


The current ratings for the typical waveforms are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

11.1 Quality information

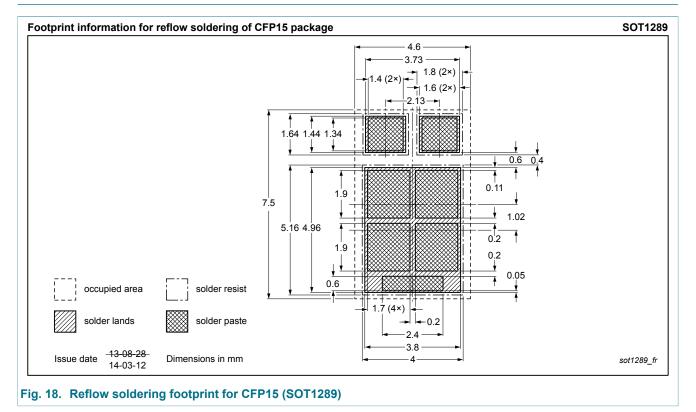
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



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14. Revision history

| Table 8. Revision his | story | | | |
|-----------------------|----------------------|------------------------------------|---------------|-----------------------|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
| PMEG045V150EPD v.4 | 20150122 | Product data sheet | - | PMEG045V150EPD v.3 |
| Modifications: | Table characteristic | s: corrected t _{rr} value | | |
| PMEG045V150EPD v.3 | 20150121 | Product data sheet | - | PMEG045V150EPD v.2 |
| PMEG045V150EPD v.2 | 20140704 | Preliminary data sheet | - | PMEG045V150EPD v.1 |
| PMEG045V150EPD v.1 | 20140519 | Objective data sheet | - | - |

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15. Legal information

15.1 Data sheet status

| Document status [1][2] | Product status [<u>3]</u> | Definition |
|--------------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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